

UNIT

V

Ω

nC

# **N-Channel Power MOSFET**

700V, 11A, 0.38Ω

#### **FEATURES**

- Super-Junction technology
- High performance due to small figure-of-merit
- High ruggedness performance
- High commutation performance

### **APPLICATION**

- Power Supply
- Lighting





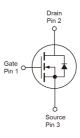
**TO-252 (DPAK)** 

PARAMETER

 $V_{DS}$ 

R<sub>DS(on)</sub> (max)

Qg



**KEY PERFORMANCE PARAMETERS** 

VALUE

700

0.38

18.8

HALOGEN FREE

Notes: Moisture sensitivity level: level 3. Per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)					
PARAMETER		SYMBOL	ITO-220	IPAK/DPAK	UNIT
Drain-Source Voltage		V <sub>DS</sub>	700		V
Gate-Source Voltage		V <sub>GS</sub>	±30		V
Continuous Drain Current (Note 1)	$T_{\rm C} = 25^{\circ}{\rm C}$		11		A
	T <sub>C</sub> = 100°C		6.6		
Pulsed Drain Current (Note 2)		I <sub>DM</sub>	33		А
Total Power Dissipation @ $T_c = 25^{\circ}C$		P <sub>DTOT</sub>	33	125	W
Single Pulsed Avalanche Energy (Note 3)		E <sub>AS</sub>	156		mJ
Single Pulsed Avalanche Current (Note 3)		I <sub>AS</sub>	2.5		А
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	- 55 to +150		°C

THERMAL PERFORMANCE				
PARAMETER	SYMBOL	ITO-220	IPAK/DPAK	UNIT
Junction to Case Thermal Resistance	R <sub>ejc</sub>	3.8	1	°C/W
Junction to Ambient Thermal Resistance	R <sub>eja</sub>	62 °C		°C/W

Notes: R<sub>0JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistances. The case thermal reference is defined at the solder mounting surface of the drain pins. R<sub>OJA</sub> is guaranteed by design while R<sub>OCA</sub> is determined by the user's board design. R<sub>0JA</sub> shown below for single device operation on FR-4 PCB in still air.





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ELECTRICAL SPECIFICA	TIONS (T <sub>A</sub> = 25°C unles	ss otherwise no	oted)			
PARAMETER	CONDITIONS	SYMBOL	MIN	ТҮР	MAX	UNIT
Static (Note 4)						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV <sub>DSS</sub>	700			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	V <sub>GS(TH)</sub>	2	3	4	V
Gate Body Leakage	$V_{GS} = \pm 30V, V_{DS} = 0V$	I <sub>GSS</sub>			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = 700 V, V_{GS} = 0 V$	I <sub>DSS</sub>			1	μA
Drain-Source On-State Resistance	$V_{GS} = 10V, I_D = 3.3A$	R <sub>DS(on)</sub>		0.33	0.38	Ω
Dynamic <sup>(Note 5)</sup>	·				•	
Total Gate Charge		Qg		18.8		
Gate-Source Charge	$V_{DS} = 380V, I_D = 11A,$	Q <sub>gs</sub>		3.7		nC
Gate-Drain Charge	V <sub>GS</sub> = 10V	Q <sub>gd</sub>		5.6		
Input Capacitance	$V_{DS} = 100V, V_{GS} = 0V,$	C <sub>iss</sub>		981		
Output Capacitance	f = 1.0MHz	C <sub>oss</sub>		58		pF
Gate Resistance	F = 1MHz, open drain	R <sub>g</sub>		3.3		Ω
Switching (Note 6)						
Turn-On Delay Time		t <sub>d(on)</sub>		32		
Turn-On Rise Time	$V_{DD} = 380V,$	t <sub>r</sub>		21		
Turn-Off Delay Time	R <sub>GEN</sub> = 35Ω, I <sub>D</sub> =11A, V <sub>GS</sub> = 10V,	t <sub>d(off)</sub>		62		ns
Turn-Off Fall Time	$D = 11A, V_{GS} = 10V,$	t <sub>f</sub>		28		
Source-Drain Diode (Note 4)						
Forward On Voltage	$I_{\rm S} = 11$ A, $V_{\rm GS} = 0$ V	V <sub>SD</sub>			1.4	V
Reverse Recovery Time	V <sub>R</sub> =200V, I <sub>S</sub> = 5.5A	t <sub>rr</sub>		226		ns
Reverse Recovery Charge	$dI_F/dt = 100A/\mu s$	Q <sub>rr</sub>		2.1		μC

Notes:

1. Current limited by package

2. Pulse width limited by the maximum junction temperature

3. L = 50mH, I<sub>AS</sub> = 2.5A, V<sub>DD</sub> = 50V, R<sub>G</sub> = 25 $\Omega$ , Starting T<sub>J</sub> = 25<sup>o</sup>C

4. Pulse test: PW  $\leq$  300µs, duty cycle  $\leq$  2%

5. For DESIGN AID ONLY, not subject to production testing.

6. Switching time is essentially independent of operating temperature.



#### **ORDERING INFORMATION**

PART NO.	PACKAGE	PACKING
TSM70N380CI C0G	ITO-220	50pcs / Tube
TSM70N380CH C5G	TO-251 (IPAK)	75pcs / Tube
TSM70N380CP ROG	TO-252 (DPAK)	2,500pcs / 13" Reel

Note:

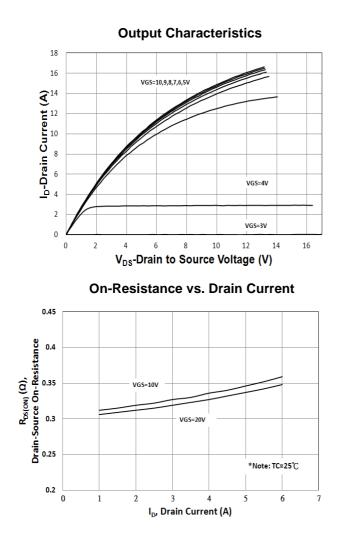
1. Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC

2. Halogen-free according to IEC 61249-2-21 definition

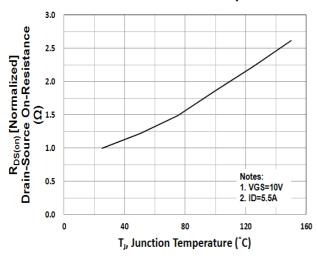


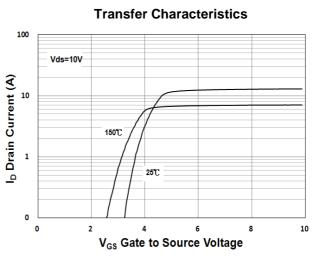
### **CHARACTERISTICS CURVES**

 $(T_c = 25^{\circ}C \text{ unless otherwise noted})$ 

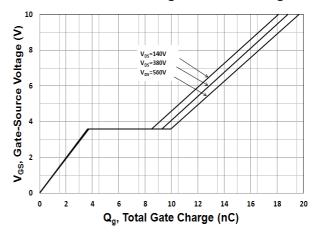




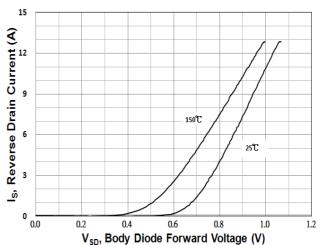




Gate-Source Voltage vs. Gate Charge



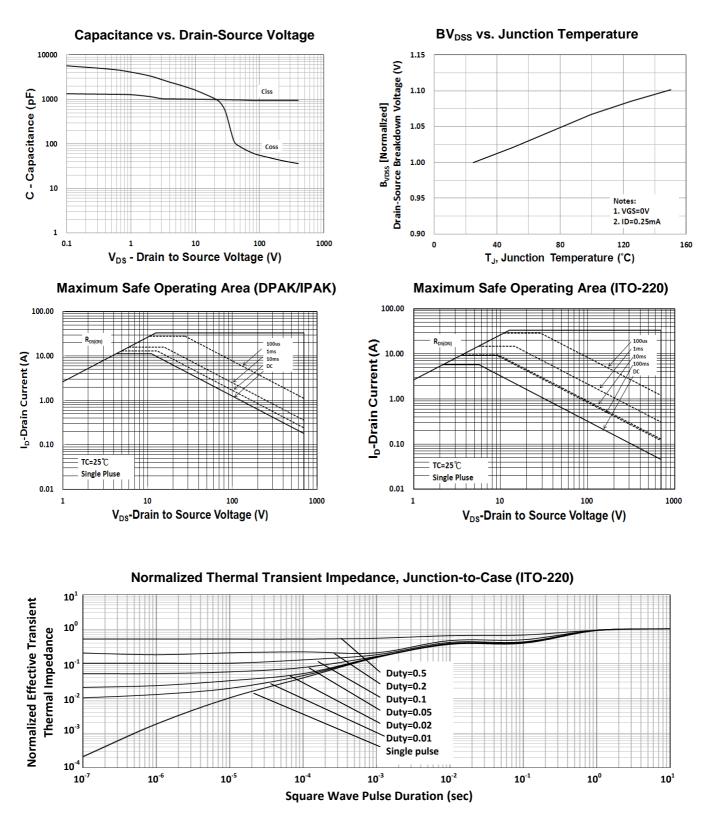
Source-Drain Diode Forward Current vs. Voltage





#### **CHARACTERISTICS CURVES**

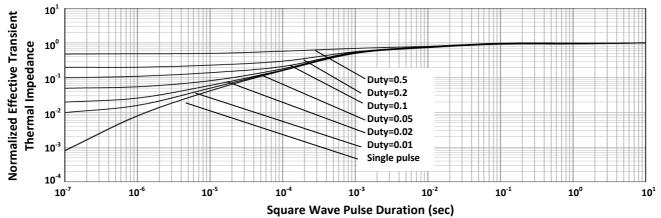
 $(T_c = 25^{\circ}C \text{ unless otherwise noted})$ 





## **ELECTRICAL CHARACTERISTICS CURVES**

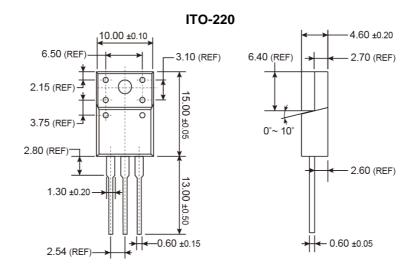
 $(T_c = 25^{\circ}C \text{ unless otherwise noted})$ 



#### Normalized Thermal Transient Impedance, Junction-to-Case (DPAK/IPAK)



### PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)



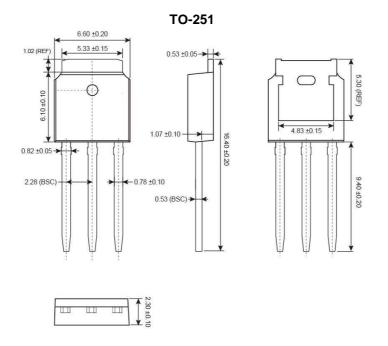
#### **MARKING DIAGRAM**



- G = Halogen Free
- Y = Year Code
- WW = Week Code (01~52)
- F = Factory Code



# PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)



#### **MARKING DIAGRAM**

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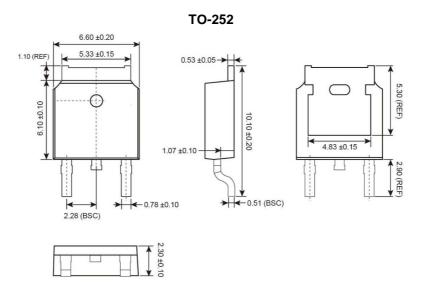
Y = Year Code			
M = Month Code	e for Haloge	n Free Prod	luct
<b>O</b> =Jan	P =Feb	<b>Q</b> =Mar	R =Apr
<b>S</b> =May	<b>T</b> =Jun	U =Jul	V =Aug
W =Sep	X =Oct	Y =Nov	Z =Dec

L = Lot Code (1~9, A~Z)

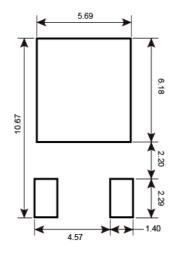




# PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)



#### SUGGESTED PAD LAYOUT (Unit: Millimeters)



#### **MARKING DIAGRAM**

$\square$	Y = Year Code
5	M = Month Code for Halogen Free Product
70N380	<b>O</b> =Jan <b>P</b> =Feb <b>Q</b> =Mar <b>R</b> =Apr
YML	S =May T =Jun U =Jul V =Aug
	W = Sep X = Oct Y = Nov Z = Dec
#1 U	L = Lot Code (1~9, A~Z)



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